

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN5006

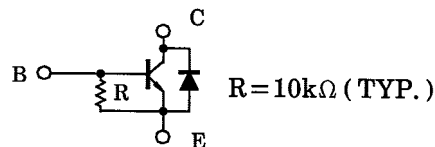
Motor Drive Circuit Applications

Power Amplifier Applications

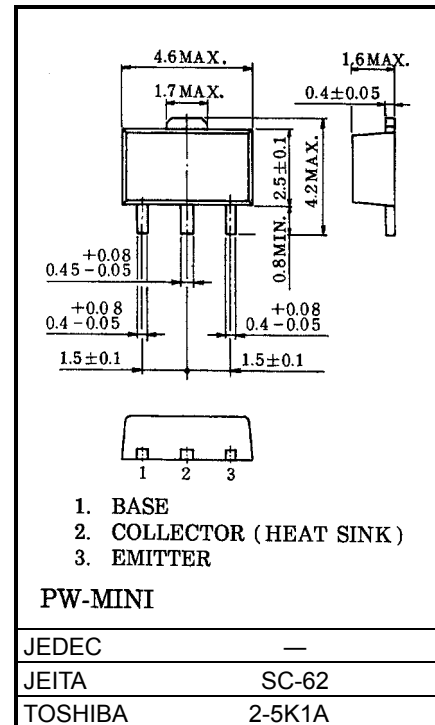
Power Switching Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Small flat package
- $P_C = 1\sim 2W$ (mounted on ceramic substrate)
- Complementary to RN6006

Equivalent Circuit



Unit: mm



Weight: 0.05g (typ.)

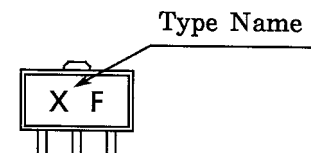
Maximum Ratings ($T_a = 25^\circ C$)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	10	V
Collector-emitter voltage		V_{CEO}	10	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I_C	2	A
	Pulse (Note1)	I_{CP}	4	
Base current		I_B	0.4	A
Collector power dissipation		P_C	500	mW
Collector power dissipation		P_C^*	1000	mW
Junction temperature		T_j	150	$^\circ C$
Storage temperature range		T_{stg}	-55~150	$^\circ C$

Note: Pulse width $\leq 10ms$, duty cycle $\leq 30\%$

* : Mounted on ceramic substrate ($250mm^2 \times 0.8t$)

Marking



Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	—	$V_{CB} = 10V, I_E = 0$	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	—	$V_{EB} = 6V, I_C = 0$	0.462	0.60	0.857	mA
Collector-emitter breakdown voltage	$V_{(BR)CES}$	—	$I_C = 1mA$	10	—	—	V
DC current gain	$h_{FE} (1)$	—	$V_{CE} = 1V, I_C = 0.5A$	160	—	600	—
	$h_{FE} (2)$		$V_{CE} = 1V, I_C = 4.0A$	60	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	$I_C = 2A, I_B = 0.05A$	—	—	0.5	V
Transition frequency	f_T	—	$V_{CE} = 1V, I_C = 0.5A$	—	140	—	MHz
Collector output capacitance	C_{ob}	—	$V_{CB} = 10V, I_E = 0, f = 1 MHz$	—	30	—	pF
Resistor	R	—	—	7	10	13	k Ω

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